

RLT980-300GS

- Infrared Laser Diode
- 980 nm, 300 mW
- Single mode





Description

RLT980-300GS is an infrared laser diode, based on InGaN quantum structures, typically emitting at 980 nm. It features single mode emission, and is TE polarized. **RLT980-300GS** comes in 9 mm TO-Can package with **integrated PD**.

Maximum Rating* (TCASE = 25°C)

| Parameter | Cumbal | Val | Unit | | |
|---------------------------------|------------------|------|-------|------|--|
| Parameter | Symbol | Min. | Max. | Unit | |
| Optical Output Power*1 | P_{MAX} | | 300 | mW | |
| Operating Temperature*2 | T_{OPR} | - 20 | + 50 | °C | |
| Storage Temperature | $T_{	t STG}$ | - 40 | + 80 | °C | |
| Soldering Temperature (max. 5s) | T _{SOL} | | + 250 | °C | |

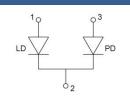


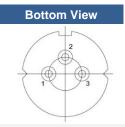
Electro-Optical Characteristics (TCASE = 25°C)

| Parameter | | Symbol | Values | | | I losis |
|---------------------------|---------------|------------------|--------|------|------|---------|
| | | | Min. | Тур. | Max. | Unit |
| Peak Wavelength | | λ_{P} | 975 | 980 | 985 | nm |
| Optical Output Power | | <i>P</i> o | | 300 | | mW |
| Spectral Width (FWHM) | | $\Delta \lambda$ | | 2.0 | | nm |
| Operating Voltage | | VF | | 1.5 | 2.0 | V |
| Threshold Current | | <i>I</i> th | | 40 | | mA |
| Operating Current | | I F | | 400 | | mA |
| Slope Efficiency | | CW | 0.70 | 0.9 | | W/A |
| Lifetime | | | 10000 | | | h |
| Beam Divergence (FWHM) | parallel | ΘII | | 8 | 10 | deg. |
| | perpendicular | Θ_{T} | | 30 | 35 | deg. |

Electrical Connection

| | Pin Configuration |
|-------|------------------------|
| Pin # | Function |
| Pin 1 | LD Anode |
| Pin 2 | LD Cathode, PD Cathode |
| Pin 3 | PD Anode |



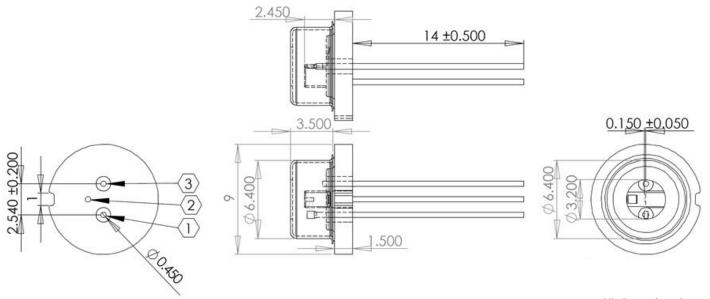


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^{*1} kink-free power, operating above may irreversibly damage the device

^{*2} operating outside these conditions may damage the device

Outline Dimensions



All dimensions in mm

Precautions

Safety

Warning: Invisible laser radiation is emitted from this device !!!

Caution: Laser light emitted from any laser diode may be harmful to the human

eye. Avoid looking directly into the laser diode's aperture when the diode

is in operation.

Note: The use of optical lenses with this laser diode will increase eye hazard

LASER RADIATION AVOID EYE OR SKIN EXPOSURE TO DIRECT OR SCATTERED RADIATION CLASS 4 LASER PRODUCT

ESD caution

Always do handle laser diodes with extreme care to **prevent electrostatic discharge**, the primary cause of unexpected diode failure. To prevent ESD related failures, it is strongly advised to always **wearing wrist straps**, and **grounding all applicable work surfaces**, when handling laser diodes

Operating Considerations

It is strongly advised to only operate this laser diode with a current source. The current of a laser diode is an exponential function of the voltage across it. **Usage of current regulated drive circuits is mandatory.** Laser diodes may be damaged by excessive drive currents or switching transients

It is advised, to operate the laser diode at the lowest temperature possible, and to never exceed maximum specifications as outlined in the datasheet. Device degradation will accelerate with increased temperature. **Proper heat sinking will greatly enhance stability and life time of the laser diode**

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The above specifications are for reference purpose only and subjected to change without prior notice.